# NSN 5961-00-403-2599

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-403-2599

# Inclosure Material:

Metal

**Overall Length:** 

1.215 inches

## Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-111

## Electrode Internally-electrically Connected To Case:

Gate

**Mounting Method:** 

Threaded stud

#### Features Provided:

#### Hermetically sealed case

**Overall Width Across Flats:** 

0.505 inches

#### Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 5.0 emitter to base voltage, static, collector open and 60.0 breakdown voltage, collector-to-emitter, base open

**Current Rating Per Characteristic:** 

10.00 amperes source cutoff current

## Power Rating Per Characteristic:

52.0 watts small-signal input power, common-collector

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

4 tab, solder lug

#### Shelf Life:

N/a

### Unit Of Measure:

---

## Demilitarization:

No

## Fiig:

A110a0